

P15F60HP2F

Power MOSFETs

600V, 15A, N-channel

Feature

- N-channel
- High Speed Source-Drain Diode
- High Speed Switching
- Low Capacitance
- High Avalanche Durability, High di/dt Durability
- Pb free terminal
- RoHS:Yes

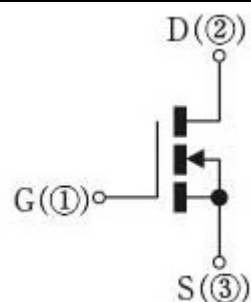
OUTLINE

Package (House Name): FTO-220AG

Package (JEITA Code): SC-91



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	T _{stg}		-55 to 150	°C
Channel temperature	T _{ch}		-55 to 150	°C
Drain-source voltage	V _{DSS}		600	V
Gate-source voltage	V _{GSS}		±30	V
Continuous drain current(DC)	I _D		15	A
Continuous drain current(Peak)	I _{DP}	Pulse width 10μs, duty=1/100	60	A
Continuous source current(DC)	I _S		15	A
Total power dissipation	P _T		95	W
Repetitive avalanche current	I _{AR}	Starting T _{ch} =25°C T _{ch} ≤150°C	15	A
Single avalanche energy	E _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	35	mJ
Repetitive avalanche energy	E _{AR}	Starting T _{ch} =25°C T _{ch} ≤150°C	3.5	mJ
Drain-source diode di/dt strength	di/dt	I _s =15A, T _c =25°C	350	A/μs
Dielectric strenght	V _{dis}	Terminals to case, AC1min	2	kV
Mounting torque	TOR	(Recommended torque : 0.3N·m)	0.5	N·m

※ :See the original Specifications

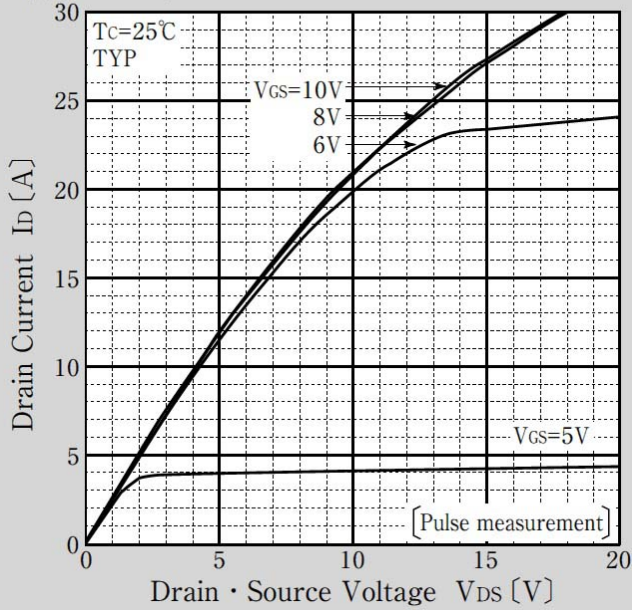
Electrical Characteristics (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	600			V
Zero gate voltage drain current	I_{DSS}	VDS=600V, VGS=0V			100	μA
Gate-source leakage current	I_{GSS}	VGS=±30V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=7.5A, VDS=10V	9	18		S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=7.5A, VGS=10V		0.44	0.53	Ω
Gate threshold voltage	V_{th}	ID=1mA, VDS=10V	2	3.25	4.5	V
Source-drain diode forward voltage	V_{SD}	IS=7.5A, VGS=0V			1.5	V
Thermal resistance	$R_{th(j-c)}$	Junction to case, with heatsink			1.32	°C/W
Total gate charge	Q_g	VDD=400V, VGS=10V, ID=15A		34		nC
Input capacitance	C_{iss}	VDS=50V, VGS=0V, f=1MHz		1720		pF
Reverse transfer capacitance	C_{rss}	VDS=50V, VGS=0V, f=1MHz		6		pF
Output capacitance	C_{oss}	VDS=50V, VGS=0V, f=1MHz		150		pF
Turn-on delay time	$t_{d(on)}$	ID=7.5A, RL=20Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V		34		ns
Rise time	t_r	ID=7.5A, RL=20Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V		40		ns
Turn-off delay time	$t_{d(off)}$	ID=7.5A, RL=20Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V		117		ns
Fall time	t_f	ID=7.5A, RL=20Ω, VDD=150V, Rg=50Ω, VGS(+)=10V, VGS(-)=0V		31		ns
Diode reverse recovery time	t_{rr}	IF=15A, VGS=0V, -di/dt=100A/μs		88		ns

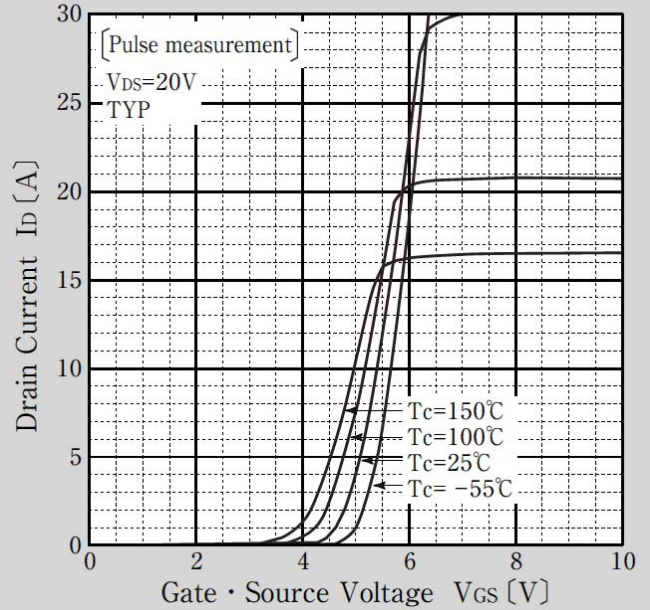
※ :See the original Specifications

CHARACTERISTIC DIAGRAMS

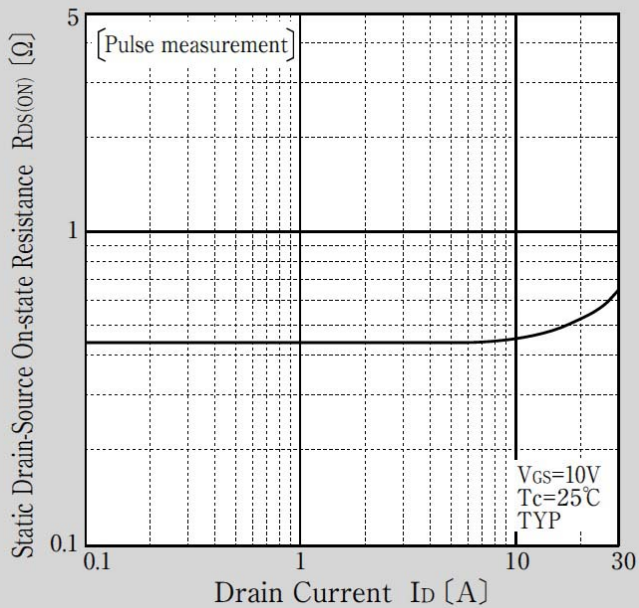
Typical Output Characteristics



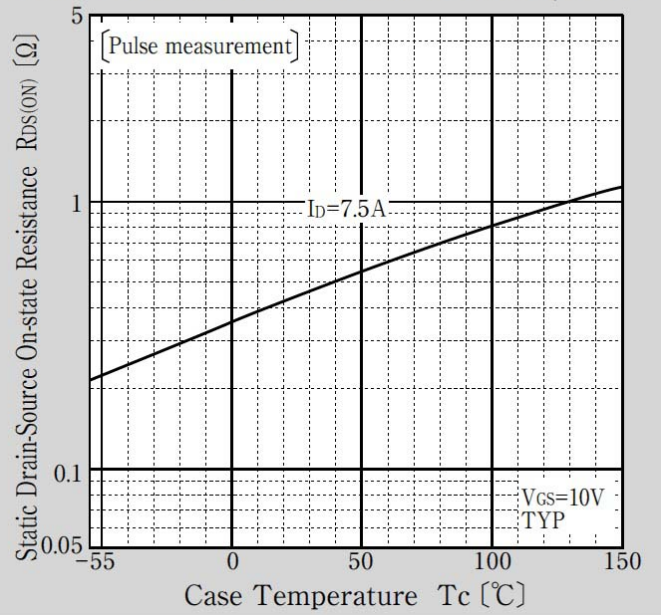
Transfer Characteristics



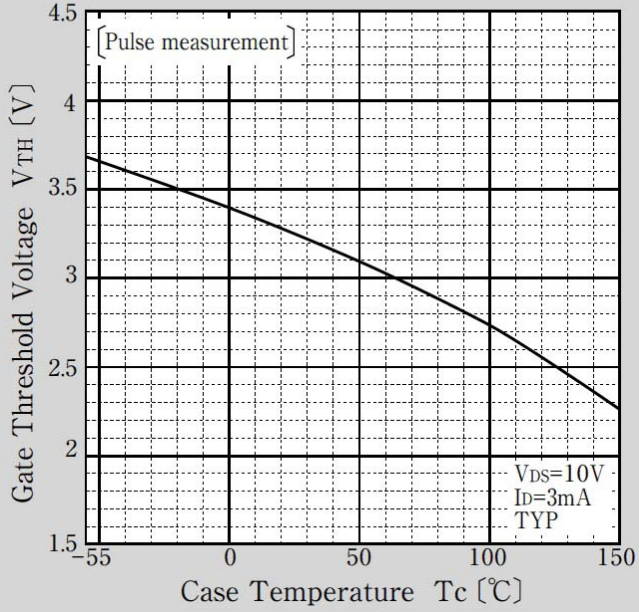
Static Drain-Source On-state Resistance vs Drain Current



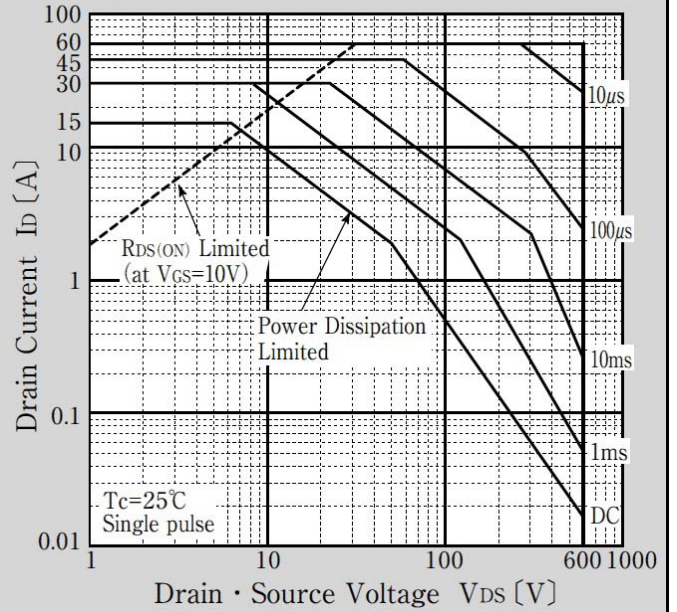
Static Drain-Source On-state Resistance vs Case Temperature



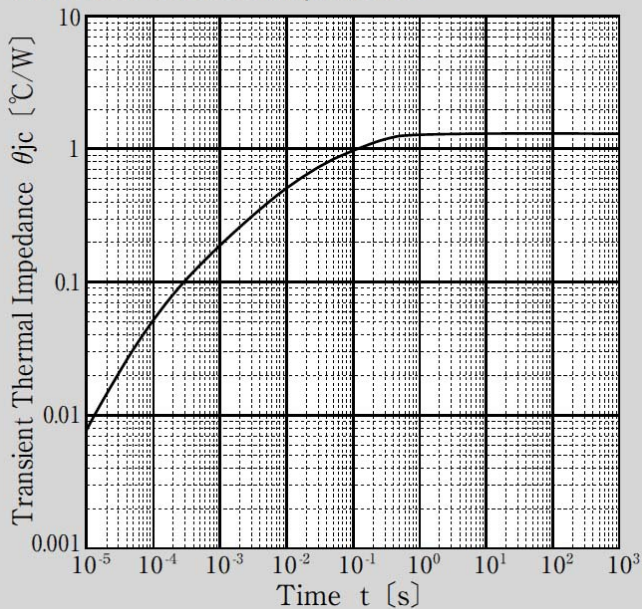
Gate Threshold Voltage vs Case Temperature



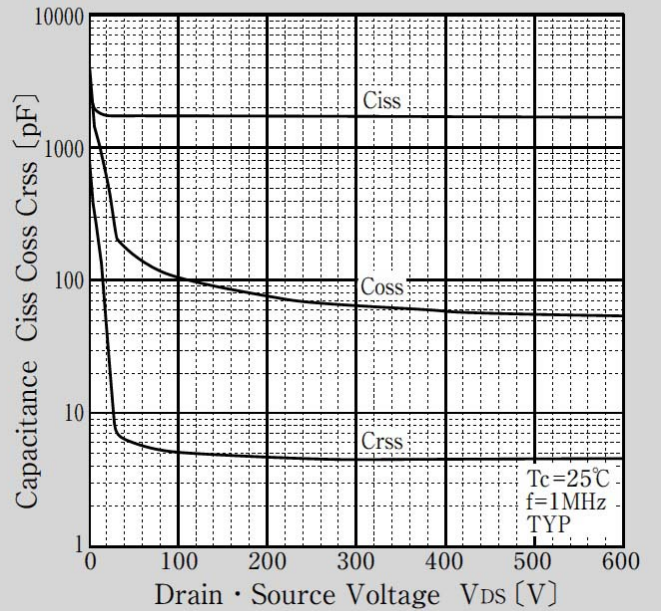
Safe Operating Area



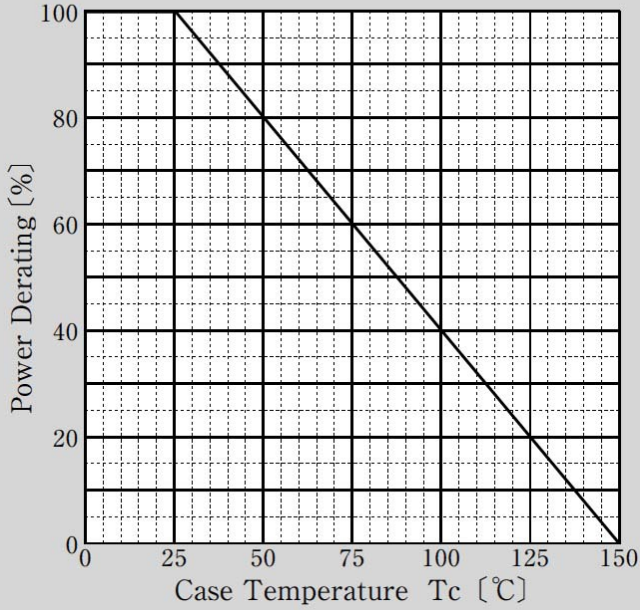
Transient Thermal Impedance



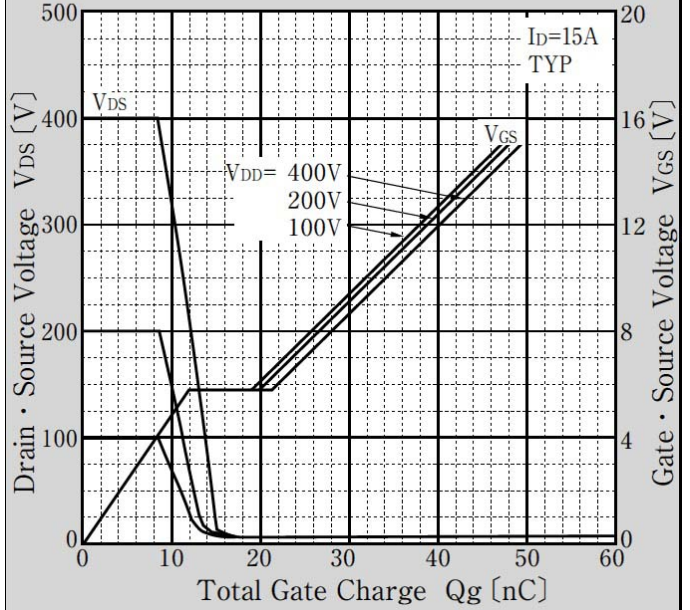
Capacitance Characteristics



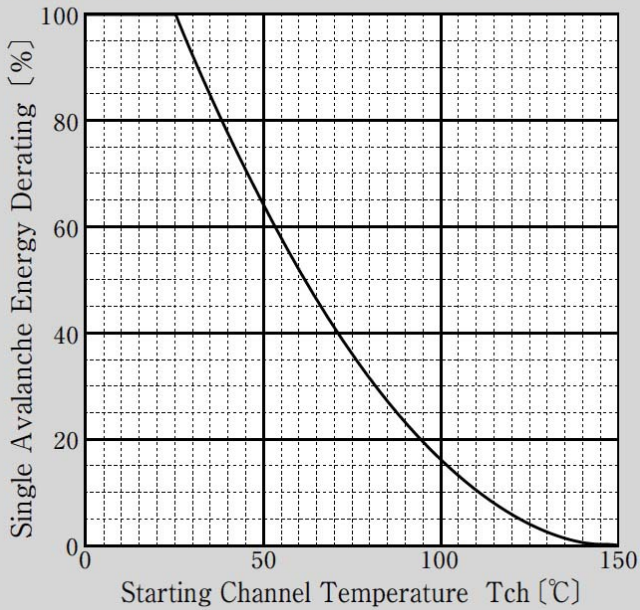
Power Derating - Case Temperature



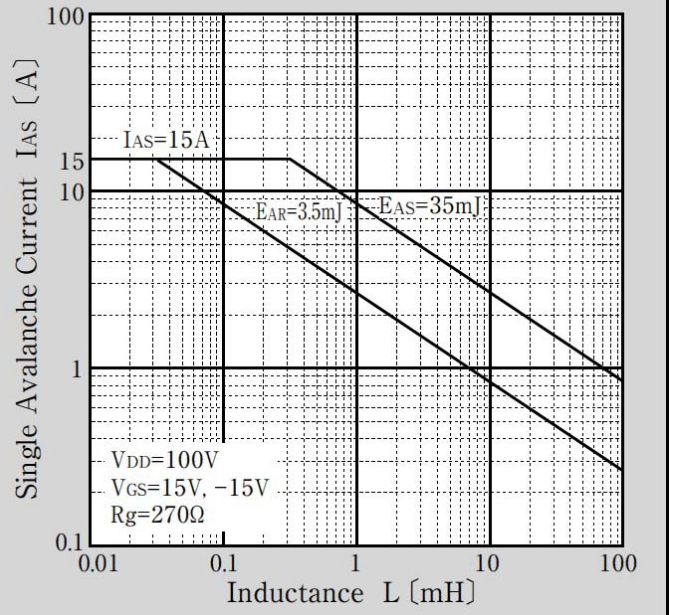
Gate Charge Characteristics



Single Avalanche Energy Derating vs Channel Temperature

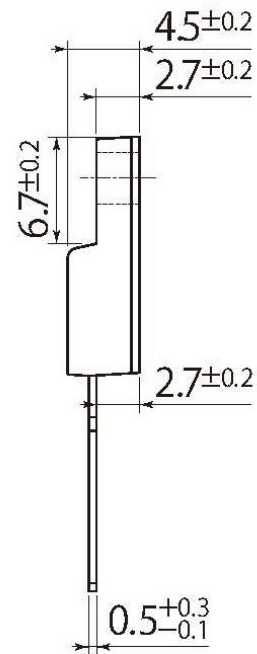
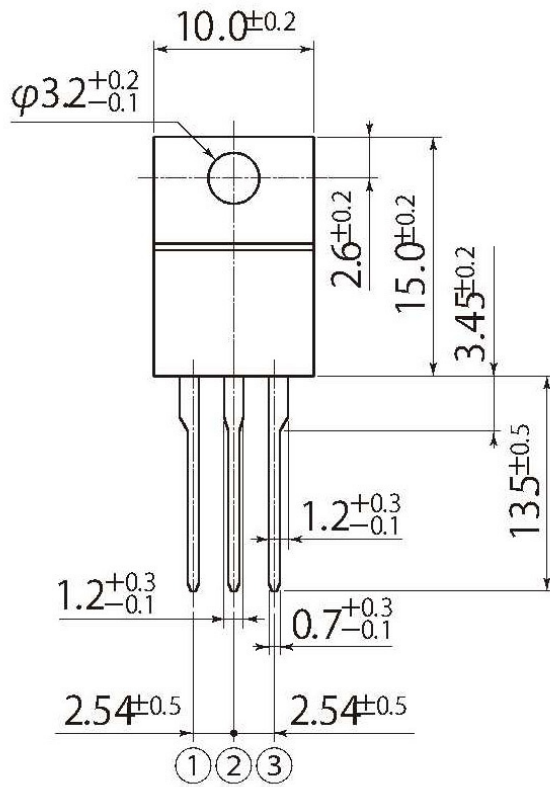


Single Avalanche Current vs Inductive Load



J8

JEDEC Code	-
JEITA Code	SC-91
House Name	FTO-220AG(3pin)



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